Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: | |
|---|-------------|
| Metal | |
| Overall Length: | |
| 1.630 inches | |
| Overall Diameter: | |
| 1.190 inches | |
| Mounting Method: | |
| Terminal | |
| Features Provided: | |
| Hermetically sealed case | |
| Semiconductor Material: | |
| Silicon | |
| Voltage Rating In Volts Per Characteristic: | |
| 1600.0 reverse voltage, peak | |
| Current Rating Per Characteristic: | |
| 600.00 milliamperes average forward current averaged over a full | 60-hz cycle |
| Maximum Operating Tempurature Per Measurement Point: | |
| 100.0 degrees celsius ambient air | |
| Terminal Type And Quantity: | |
| 1 electron tube base | |
| Specification Data: | |
| 80131-release4155 professional/industrial association specification | I |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| No | |
| Fiig: | |
| A110a0 | |
| | |
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